

August 1999 Revised May 2005

# 74ACT16245 16-Bit Transceiver with 3-STATE Outputs

## **General Description**

The ACT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each has separate control inputs which can be shorted together for full 16-bit operation. The  $T/\overline{R}$  inputs determine the direction of data flow through the device. The  $\overline{OE}$  inputs disable both the A and B ports by placing them in a high impedance state.

#### **Features**

- Bidirectional non-inverting buffers
- Separate control logic for each byte
- 16-bit version of the ACT245
- Outputs source/sink 24 mA
- TTL-compatible inputs

# **Ordering Code:**

Order Number	Package Number	Package Description
74ACT16245SSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ACT16245MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

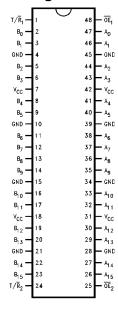
## **Logic Symbol**



## **Pin Description**

Pin Names	Description				
<del>OE</del> <sub>n</sub>	Output Enable Input (Active LOW)				
T/R	Transmit/Receive Input				
A <sub>0</sub> -A <sub>15</sub> B <sub>0</sub> -B <sub>15</sub>	Side A Inputs/Outputs				
B <sub>0</sub> -B <sub>15</sub>	Side B Outputs/Inputs				

# **Connection Diagram**



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# **Functional Description**

The ACT16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the  $T/\overline{R}$  input is  $\underline{H}IGH$ , then Bus A data is transmitted to Bus B. When the  $T/\overline{R}$  input is LOW,

Bus B data is transmitted to Bus A. The 3-STATE outputs are controlled by an Output Enable  $(\overline{OE}_n)$  input for each byte. When  $\overline{OE}_n$  is LOW, the outputs are in 2-state mode. When  $\overline{\text{OE}}_{n}$  is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

#### **Truth Tables**

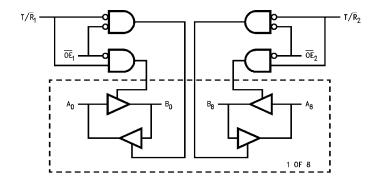
Inp	outs	Outputs		
ŌE <sub>1</sub>	T/R <sub>1</sub>			
L	L	Bus B <sub>0</sub> –B <sub>7</sub> Data to Bus A <sub>0</sub> –A <sub>7</sub>		
L	Н	Bus A <sub>0</sub> –A <sub>7</sub> Data to Bus B <sub>0</sub> –B <sub>7</sub>		
Н	X	HIGH-Z State on A <sub>0</sub> -A <sub>7</sub> , B <sub>0</sub> -B <sub>7</sub>		

Inputs		Outputs				
$\overline{\text{OE}}_2$ $\overline{\text{T/R}}_2$						
L	L	Bus B <sub>8</sub> -B <sub>15</sub> Data to Bus A <sub>8</sub> -A <sub>15</sub>				
L	Н	Bus A <sub>8</sub> -A <sub>15</sub> Data to Bus B <sub>8</sub> -B <sub>15</sub>				
Н	Χ	HIGH-Z State on A <sub>8</sub> -A <sub>15</sub> , B <sub>8</sub> -B <sub>15</sub>				

- H = HIGH Voltage Level L = LOW Voltage Level

- X = Immaterial Z = High Impedance

# **Logic Diagram**



# **Absolute Maximum Ratings**(Note 1)

-0.5V to + 7.0V Supply Voltage (V<sub>CC</sub>)

DC Input Diode Current (I<sub>IK</sub>)

 $V_1 = -0.5V$ -20 mA  $V_I = V_{CC} + 0.5V$ +20 mA

DC Output Diode Current (I<sub>OK</sub>)

 $V_0 = -0.5V$ -20 mA  $V_O = V_{CC} + 0.5V$ +20 mA DC Output Voltage (V<sub>O</sub>) –0.5V to  $V_{CC}$  +0.5V  $\pm$  50 mA

DC Output Source/Sink Current (IO)

DC V<sub>CC</sub> or Ground Current

per Output Pin  $\pm$  50 mA Storage Temperature -65°C to +150°C

## **Recommended Operating Conditions**

Supply Voltage (V<sub>CC</sub>) 4.5V to 5.5V Input Voltage (V<sub>I</sub>) 0V to  $V_{\mbox{\footnotesize CC}}$ Output Voltage (V<sub>O</sub>) 0V to  $V_{\mbox{\footnotesize CC}}$ Operating Temperature (T<sub>A</sub>) -40°C to +85°C Minimum Input Edge Rate  $(\Delta V/\Delta t)$ 125 mV/ns

 $V_{\text{IN}}$  from 0.8V to 2.0V

V<sub>CC</sub> @ 4.5V, 5.5V

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, with-out exception to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT  $^{\text{\tiny{TM}}}$  circuits outside databook specifications.

### **DC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub>	V <sub>CC</sub> T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to+85°C	Units	Conditions	
Зуппоп	Farameter	(V)	Тур	p Guaranteed Limits		Units		
V <sub>IH</sub>	Minimum HIGH	4.5	1.5	2.0	2.0	V	V <sub>OUT</sub> = 0.1V	
	Input Voltage	5.5	1.5	2.0	2.0	v	or V <sub>CC</sub> - 0.1V	
V <sub>IL</sub>	Maximum LOW	4.5	1.5	0.8	0.8	V	V <sub>OUT</sub> = 0.1V	
	Input Voltage	5.5	1.5	0.8	0.8	v	or V <sub>CC</sub> - 0.1V	
V <sub>OH</sub>	Minimum HIGH		4.49	4.4	4.4	V	. 50 4	
	Output Voltage	5.5	5.49	5.4	5.4	V	I <sub>OUT</sub> = -50 μA	
							$V_{IN} = V_{IL}$ or $V_{IH}$	
		4.5		3.86	3.76	V	$I_{OH} = -24 \text{ mA}$	
		5.5		4.86	4.76		$I_{OH} = -24 \text{ mA (Note 2)}$	
V <sub>OL</sub>	Maximum LOW	4.5	0.001	0.1	0.1	V	Ι <sub>ΟΙΙΤ</sub> = 50 μΑ	
	Output Voltage	5.5	0.001	0.1	0.1	· ·	IOUT - 20 try	
							$V_{IN} = V_{IL}$ or $V_{IH}$	
		4.5		0.36	0.44	V	I <sub>OL</sub> = 24 mA	
		5.5		0.36	0.44		I <sub>OL</sub> = 24 mA (Note 2)	
I <sub>OZT</sub>	Maximum I/O	5.5		±0.5	±5.0	μА	$V_I = V_{IL}, V_{IH}$	
	Leakage Current 5.5			±0.5	±3.0	μА	$V_O = V_{CC}$ , GND	
I <sub>IN</sub>	Maximum Input	5.5	±0.1	±1.0	μА	V <sub>I</sub> = V <sub>CC</sub> , GND		
	Leakage Current	5.5		±0.1	±1.0	μА	VI = VCC, GIND	
I <sub>CCT</sub>	Maximum I <sub>CC</sub> /Input	5.5	0.6		1.5	mA	$V_I = V_{CC} - 2.1V$	
Icc	Max Quiescent		5.5	0.0	80.0	^	V V as CND	
	Supply Current			8.0	60.0	μА	$V_{IN} = V_{CC}$ or GND	
I <sub>OLD</sub>	Minimum Dynamic	5.5			75	mA	V <sub>OLD</sub> = 1.65V Max	
I <sub>OHD</sub>	Output Current (Note 3)				-75	mA	V <sub>OHD</sub> = 3.85V Min	

Note 2: All outputs loaded; thresholds associated with output under test.

Note 3: Maximum test duration 2.0 ms; one output loaded at a time.

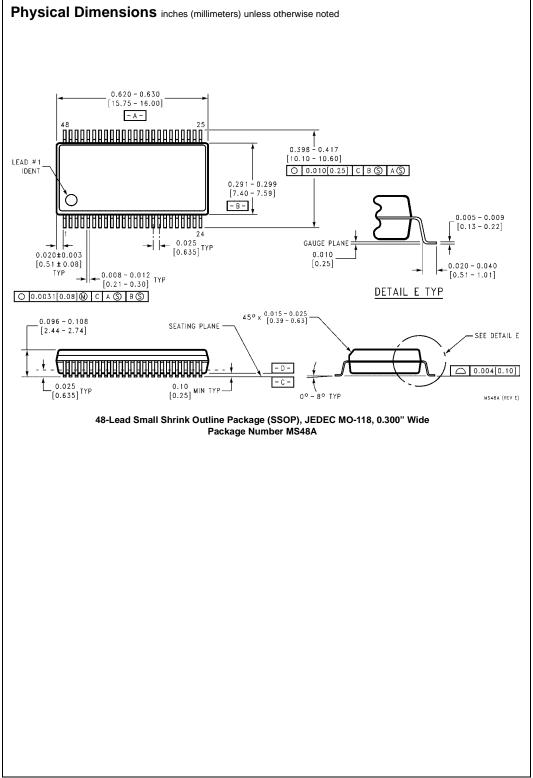
# **AC Electrical Characteristics**

		V <sub>CC</sub>	T <sub>A</sub> = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			
Symbol	Parameter	(V)	C <sub>L</sub> = 50 pF			$C_L = 50 \text{ pF}$		Units	
		(Note 4)	Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation	5.0	3.2	5.7	8.4	3.2	9.0	20	
t <sub>PHL</sub>	Delay A <sub>n</sub> , B <sub>n</sub> to B <sub>n</sub> , A <sub>n</sub>		2.6	5.1	7.9	2.6	8.4	ns	
t <sub>PZH</sub>	Output Enable	5.0	3.7	6.4	9.4	2.7	10.0	20	
t <sub>PZL</sub>	Time		4.1	7.4	10.5	3.4	11.6	ns	
t <sub>PHZ</sub>	Output Disable	5.0	2.2	5.4	8.7	2.2	9.3	20	
t <sub>PLZ</sub>	Time		2.0	5.2	8.2	2.0	8.8	ns	

Note 4: Voltage Range 5.0 is 5.0V ± 0.5V.

# Capacitance

Symbol	Parameter	Тур	Units	Conditions
C <sub>IN</sub>	Input Pin Capacitance	4.5	pF	V <sub>CC</sub> = 5.0V
C <sub>PD</sub>	Power Dissipation Capacitance	25	pF	V <sub>CC</sub> = 5.0V



## Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 12.50±0.10 0.40 TYP -B-10±0,10 99 9.20 B.10 50. O.2 C B A ALL LEAD TIPS PIN #1 IDENT LAND PATTERN RECOMMENDATION O.1 C SEE DETAIL A 0.90+0.15 0.09-0.20 0.10±0.05 0.50 0.17-0.27 ♦ 0.13\( \old{\text{0}} \) A B\( \old{\text{S}} \) C\( \old{\text{S}} \) 12.00' TOP & BOTTOM DIMENSIONS ARE IN MILLIMETERS GAGE PLANE 0.25 NOTES A. CONFORMS TO JEDEC REGISTRATION MC-153, VARIATION ED, DATE 4/97. B. DIMENSIONS ARE IN MILLIMETERS. SEATING PLANE 0.60±0.10 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS. D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982. DETAIL A MTD48REVC

48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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